NSN 5962-01-089-8975

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/psn/5062-01-080-8075

view Online at https://aerobasegroup.com/hsh/5962-01-069-6975
Body Length:
Between 1.995 inches and 2.005 inches
Body Width:
Between 0.495 inches and 0.505 inches
Maximum Power Dissipation Rating:
1.8 watts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Wsd: integrated underwater surveillance systems
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and 2-phase
Inclosure Material:
Ceramic and metal
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
9 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.2 volts power source and 20.0 volts power source
Time Rating Per Chacteristic:
100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Terminal Type And Quantity:
40 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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